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NTE75188 Integrated Circuit Diode Transistor Logic (DTL) Quad Line Driver

Description:

The NTE75188 is a monolithic quadruple line driver in a 14-Lead DIP type package designed to interface data terminal equipment with data communications equipment in conformance with EIA Standard RS-232-C using a diode in series with each supply-voltage terminal.

Features:

- Meets Specifications of EIA RS-232-C
- Current-Limited Output: 10mA Typ
- Power-Off Output Impedance: 300Ω Min
- Slew Rate Control by Load Capacitor
- Flexible Supply Voltage Range
- Input Compatible with Most TTL Circuits

Absolute Maximum Ratings: ($T_A = 0$ to $+70^\circ\text{C}$ unless otherwise specified)

Supply Voltage ($T_A \leq +25^\circ\text{C}$, Note 1)

V_{CC}	+15V
V_{EE}	-15V

Input Voltage Range

-15V to +7V

Output Voltage Range

-15V to +15V

Continuous Total Dissipation ($T_A \leq +25^\circ\text{C}$), P_D

1025mW

Operating Ambient Temperature range, T_A

0 to $+70^\circ\text{C}$

Storage Temperature Range, T_{stg}

-65° to +150°C

Lead Temperature (During Soldering 1/16" (1.6mm) from case, 60sec Max), T_L

+300°C

Note 1. All voltage values are with respect to the network GND pin.

Recommended Operating Conditions:

Parameter	Symbol	Min	Typ	Max	Unit
Supply Voltage	V_{CC}	7.5	9.0	15.0	V
	V_{EE}	-7.5	-9.0	-15.0	V
High Level Input Voltage	V_{IH}	1.9	-	-	V
Low Level Input Voltage	V_{IL}	-	-	0.8	V
Operating Ambient Temperature	T_A	0	-	+70	°C

Electrical Characteristics: ($T_A = 0$ to $+70^\circ\text{C}$, $V_{CC} = 9\text{V}$, $V_{EE} = -9\text{V}$ unless otherwise specified)

Parameter	Symbol	Test Conditions		Min	Typ	Max	Unit
High Level Output Voltage	V_{OH}	$V_{IL} = 800\text{mV}$, $R_L = 3\text{k}\Omega$	$V_{CC} = 9\text{V}$, $V_{EE} = -9\text{V}$	6	7	-	V
			$V_{CC} = 13.2\text{V}$, $V_{EE} = -13.2\text{V}$	9.0	10.5	-	V
Low Level Output Voltage	V_{OL}	$V_{IH} = 1.9\text{V}$, $R_L = 3\text{k}\Omega$	$V_{CC} = 9\text{V}$, $V_{EE} = -9\text{V}$	-	-7	-6	V
			$V_{CC} = 13.2\text{V}$, $V_{EE} = -13.2\text{V}$	-	-10.5	-9.0	V
High Level Input Current	I_{IH}	$V_I = 5\text{V}$		-	-	10	μA
Low Level Input Current	I_{IL}	$V_I = 0$		-	-1.0	-1.6	mA
Short Circuit Output Current at High Level	$I_{OS(H)}$	$V_I = 800\text{mV}$, $V_O = 0$, Note 3		-6	-9	-12	mA
Short Circuit Output Current at Low Level	$I_{OS(L)}$	$V_I = 1.9\text{V}$, $V_O = 0$, Note 3		6	9	12	mA
Output Resistance, Power Off	r_o	$V_{CC} = 0$, $V_{EE} = 0$, $V_O = -2\text{V}$ to $+2\text{V}$		300	-	-	Ω
Supply Current from V_{CC}	I_{CC}	$V_{CC} = 9\text{V}$, No Load	All Inputs at 1.9V	-	15	20	mA
			All Inputs at 800mV	-	4.5	6.0	mA
		$V_{CC} = 12\text{V}$, No Load	All Inputs at 1.9V	-	19	25	mA
			All Inputs at 800mV	-	5.5	7.0	mA
		$V_{CC} = 15\text{V}$, No Load, $T_A = +25^\circ\text{C}$	All Inputs at 1.9V	-	-	34	mA
			All Inputs at 800mV	-	-	12	mA
Supply Current from V_{EE}	I_{EE}	$V_{EE} = -9\text{V}$, No Load	All Inputs at 1.9V	-	-13	-17	mA
			All Inputs at 800mV	-	-	-0.015	mA
		$V_{EE} = -12\text{V}$, No Load	All Inputs at 1.9V	-	-18	-23	mA
			All Inputs at 800mV	-	-	-0.015	mA
		$V_{EE} = -15\text{V}$, No Load, $T_A = +25^\circ\text{C}$	All Inputs at 1.9V	-	-	-34	mA
			All Inputs at 800mV	-	-	-2.5	mA
Total Power Dissipation	P_D	$V_{CC} = 9\text{V}$, $V_{EE} = -9\text{V}$, No Load		-	-	333	mW
		$V_{CC} = 12\text{V}$, $V_{EE} = -12\text{V}$, No Load		-	-	576	mW

Note 2. All typical values are at $T_A = +25^\circ\text{C}$.

Note 3. Not more than one output should be shorted at a time.

Note 4. The algebraic convention in which the less positive (more negative) limit is designated as minimum, is used in this data sheet for logic voltage levels only, e.g., if -6V is a maximum, the typical value is a more negative voltage.

Switching Characteristics: ($T_A = +25^\circ\text{C}$, $V_{CC} = 9\text{V}$, $V_{EE} = -9\text{V}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Propagation Delay Time, Low-to-High-Level Output	t_{PLH}	$R_L = 3\text{k}\Omega$, $C_L = 15\text{pF}$	-	220	350	ns
Propagation Delay Time, High-to-Low-Level Output	t_{PHL}		-	100	175	ns
Transition Time, Low-to-High Level Output	t_{TLH}	Note 5	-	55	100	ns
Transition Time, High-to-Low Level Output	t_{THL}		-	45	75	ns
Transition Time, Low-to-High Level Output	t_{TLH}	$R_L = 3\text{k}\Omega$ to $7\text{k}\Omega$, $C_L = 2500\text{pF}$, Note 6	-	2.5	-	ns
Transition Time, High-to-Low Level Output	t_{THL}		-	3.0	-	ns

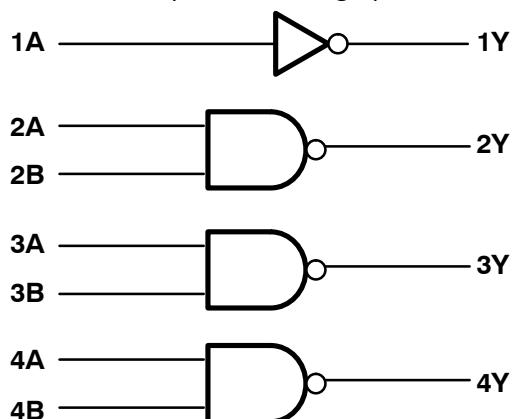
Note 5. Measured between 10% and 90% points of output waveform.

Note 6. Measured between $+3\text{V}$ and -3V points on the output waveform.

Function Table:
(Drivers 2 thru 4)

A	B	Y
H	H	L
L	X	H
X	L	H

Logic Diagram
(Positive Logic)



Positive Logic
 $Y = \bar{A}$ (Driver 1)
 $Y = \bar{AB}$ or $\bar{A} + \bar{B}$ (Drivers 2 thru 4)

Pin Connection Diagram

